

# RJK2017DPP-M0

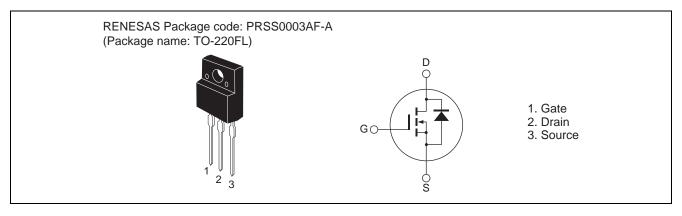
200V - 45A - MOS FET High Speed Power Switching R07DS0664EJ0100 Rev.1.00 Feb 03, 2012

Datasheet

## Features

- Low on-resistance
  - $R_{DS(on)} = 0.036 \ \Omega \text{ typ.}$  (at  $I_D = 22.5 \text{ A}$ ,  $V_{GS} = 10 \text{ V}$ ,  $Ta = 25^{\circ}\text{C}$ )
- Low leakage current
- High speed switching

#### Outline



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	200	V
Gate to source voltage	V <sub>GSS</sub>	±30	V
Drain current	ID Note4	45	А
Drain peak current	I <sub>D (pulse)</sub> Note1	135	А
Body-drain diode reverse drain current	I <sub>DR</sub>	45	А
Avalanche current	I <sub>AP</sub> Note3	12	А
Avalanche energy	E <sub>AR</sub> <sup>Note3</sup>	9.6	mJ
Channel dissipation	Pch Note2	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	٥°
Storage temperature	Tstg	-55 to +150	٥°

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tc =  $25^{\circ}C$ 

- 3. STch = 25°C, Tch  $\leq$  150°C
- 4. Limited by maximum safe operation area



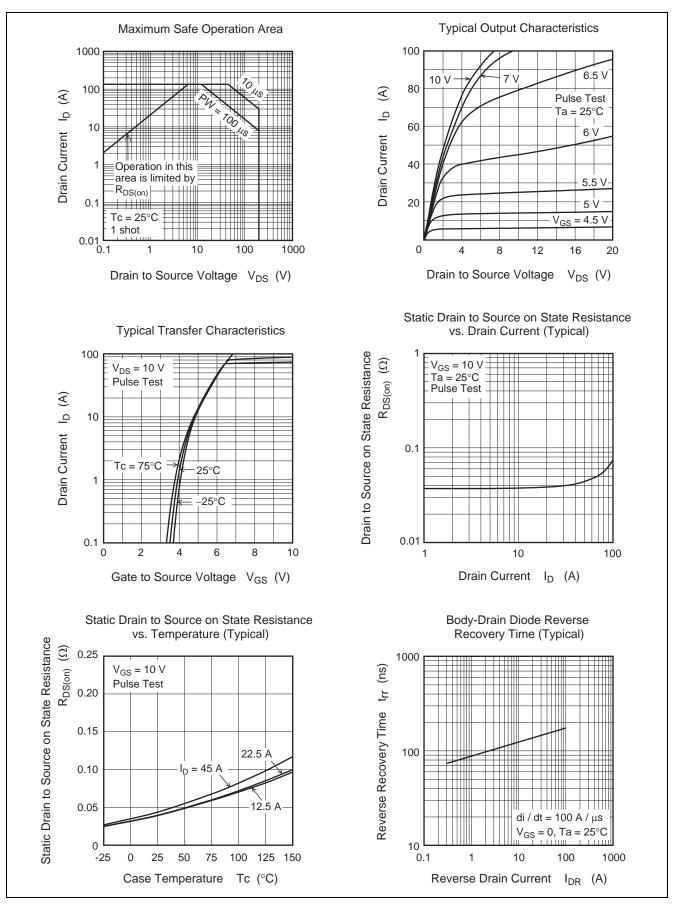
# **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	200		—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_		1	μΑ	$V_{DS} = 200 V, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±1	μΑ	$V_{GS}=\pm 30~V,~V_{DS}=0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2	_	4	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.036	0.047	Ω	$I_D = 22.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$
resistance						
Input capacitance	Ciss	_	4800	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss		290	—	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss		90	—	рF	
Turn-on delay time	t <sub>d(on)</sub>	_	50	—	ns	I <sub>D</sub> = 22.5 A
Rise time	tr	_	40	—	ns	V <sub>GS</sub> = 10 V
Turn-off delay time	t <sub>d(off)</sub>	_	95	—	ns	R <sub>L</sub> = 4.5 Ω Rg = 10 Ω
Fall time	t <sub>f</sub>	_	40	—	ns	
Total gate charge	Qg	_	66	—	nC	V <sub>DD</sub> = 160 V
Gate to source charge	Qgs	_	26	_	nC	V <sub>GS</sub> = 10 V I <sub>D</sub> = 45 A
Gate to drain charge	Qgd	_	16		nC	
Body-drain diode forward voltage	V <sub>DF</sub>	_	0.88	1.35	V	$I_F = 45 \text{ A}, V_{GS} = 0^{\text{Note5}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	150	—	ns	$I_F = 45 \text{ A}, V_{GS} = 0$
						$di_F/dt = 100 \text{ A}/\mu \text{s}$

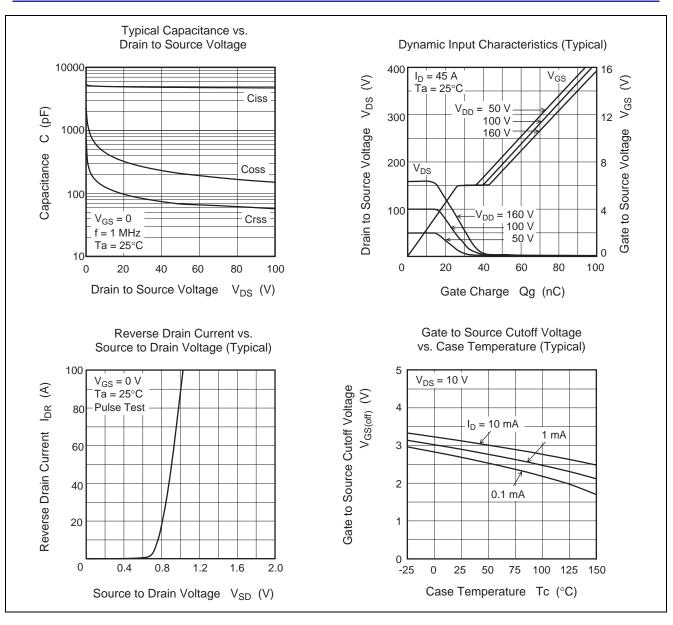
Notes: 5. Pulse test



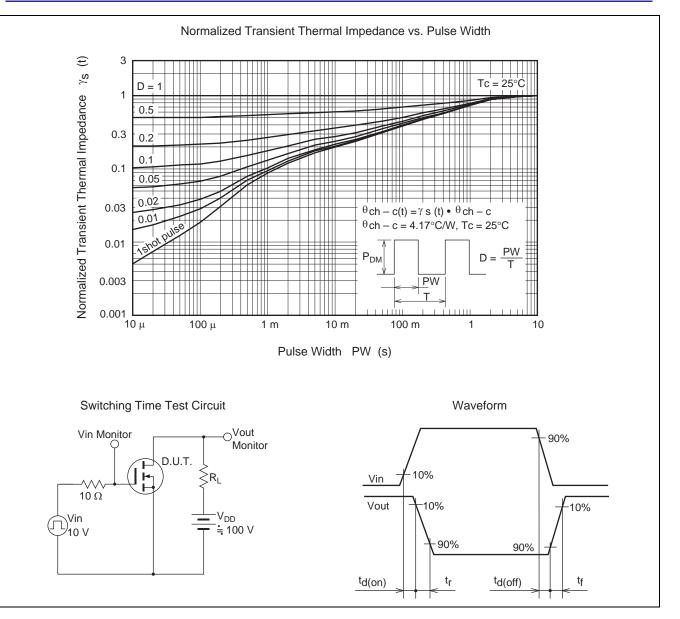
#### **Main Characteristics**





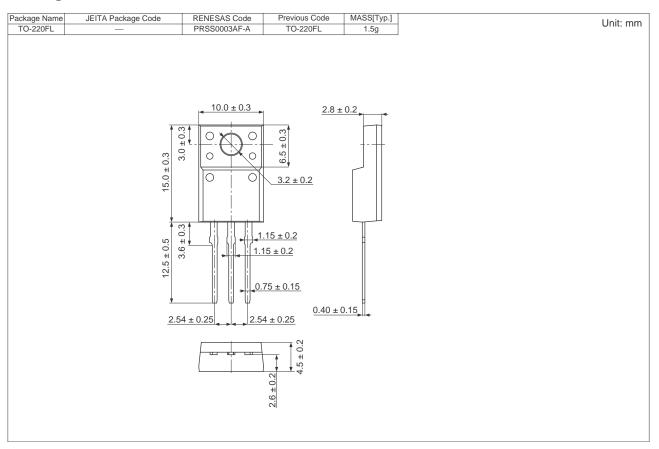








### **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK2017DPP-M0#T2	600 pcs	Box (Tube)



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